

LNC707PS

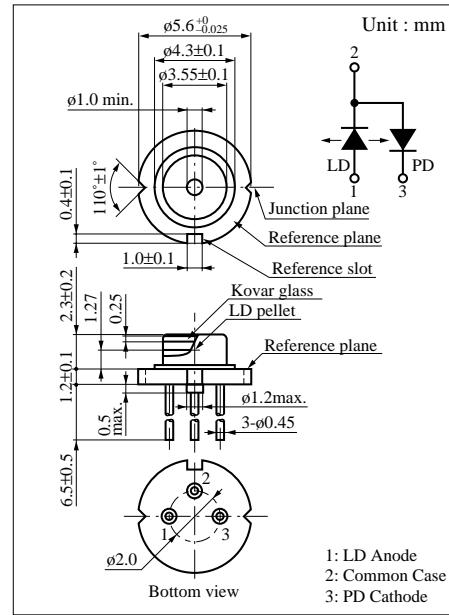
High Power Output Semiconductor Laser

■ Overview

The LNC707PS is a near infrared GaAlAs laser diode which provides continuous oscillation in single mode and is stable at low operating current. LNC707PS uses a small package, and is capable of operating continuously at high temperatures with high output (60 mW). It can be used in a wide range of applications as a light source for optical disk memory and optical information devices. In particular, it can be used in making equipment portable due to its low current operations.

■ Features

- Low current operations : 70 mA (with 60 mW output)
- High power output : 60 mW
- Stable single horizontal mode oscillation
- Small size package



■ Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
Radiant power	P_O	60	mW
Reverse voltage	Laser V_R	2	V
	PIN V_R (PIN)	30	V
Power dissipation	P_d (PIN)	100	mW
Operating ambient temperature	T_{opr}	-10 to +60	°C
Storage temperature	T_{stg}	-40 to +80	°C

■ Electro-Optical Characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	min	typ	max	Unit
Threshold current	I_{th}	CW	15	25	35	mA
Operating current	I_{OP}	$P_O = 60\text{mW}$	70	100	130	mA
Operating voltage	V_{OP}	$P_O = 60\text{mW}$		2.0	2.5	V
Oscillation wavelength	λ_L	$P_O = 60\text{mW}$	778	784	790	nm
Radiation angle	Horizontal direction $\theta_{//}^*$	$P_O = 60\text{mW}$	7	10	13	deg.
	Vertical direction θ_{\perp}^*	$P_O = 60\text{mW}$	17	21	25	deg.
Differential efficiency	η	$P_O = 55\text{mW}/I(60\text{mW} - 5\text{mW})$	0.7	0.9	1.2	mW/mA
Reverse current (DC)	I_R	V_R (PIN) = 5V			0.1	μA
PIN photo current	I_P	$P_O = 60\text{mW}, V_R$ (PIN) = 5V		0.2		mA
Optical axis accuracy	X direction θ_X	$P_O = 60\text{mW}$	-2.0		+2.0	deg.
	Y direction θ_Y	$P_O = 50\text{mW}$	-3.0		+3.0	deg.
Oscillation mode		Single horizontal mode				

* $\theta_{//}$ and θ_{\perp} are the angles where the optical intensity is a half of its max. value.(half full angle)

